

## 6-18GHz 4 bit Digital Variable Amplifier

GaAs Monolithic Microwave IC

*preliminary*

### Description

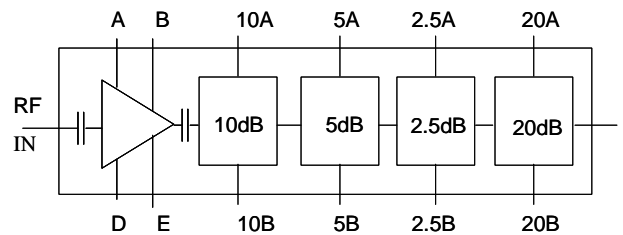
The CHA3514 is composed by a two stage travelling wave amplifier followed by a four steps digital attenuator. It is designed for defense applications. The backside of the chip is both RF and DC grounded. This helps to simplify the assembly process.

The circuit is manufactured with a PM-HEMT process, 0.25 $\mu$ m gate length, via holes through the substrate, air bridges and electron beam gate lithography.

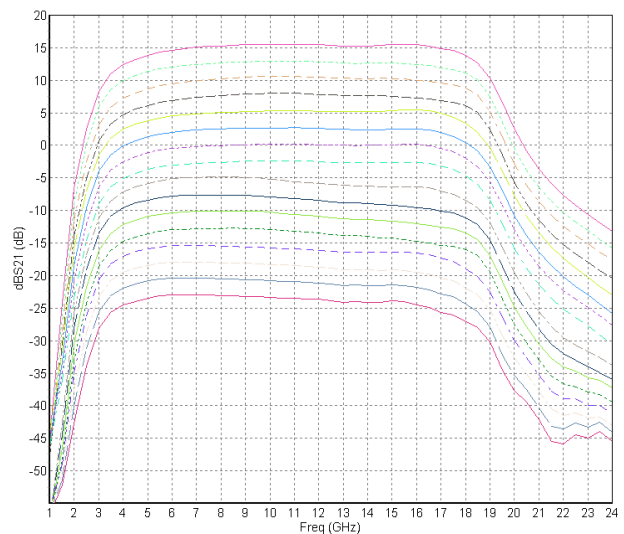
It is available in chip form.

### Main Features

- Performances: 6-18GHz
- 19dBm saturated output power
- 13 dB gain
- 4bit attenuator for 39.5dB dynamic range
- DC power consumption, 190mA @ 4.5V
- Chip size: 5.54 x 2.30 x 0.1 mm



**Typical on wafer Measurements**  
Gain versus attenuation states



### Main Characteristics

Tamb. = 25°C

Symbol	Parameter	Min	Typ	Max	Unit
Fop	Operating frequency range	6		18	GHz
G	Small signal gain @ Attenuator state 0dB		13		dB
Psat	Saturated Output power @ Attenuator state 0dB		19		dBm
ATT dyn	Attenuator range with 4bit		39.5		dB

ESD Protection: Electrostatic discharge sensitive device. Observe handling precautions!

*preliminary*

## Electrical Characteristics on wafer

Tamb = +25°C

Vd= Pads B, D= 4.5V, Vg= Pads A, E tuned for Id= 190mA

Symbol	Parameter	Min	Typ	Max	Unit
Fop	Operating frequency range (1)	6		18	GHz
G	Small signal gain @ Attenuator state 0dB (1)		13		dB
ATT bit	Attenuator bit: State 2.5dB		2.6		dB
	State 5dB		5		dB
	State 10 dB		10		dB
	State 20dB		22		dB
ATT dyn	Attenuator dynamic range with 4bit		39.5		dB
P1dB	Output power at 1dB compression @ Attenuator state 0dB (1)		18		dBm
Psat	Saturated Output power @ Attenuator state 0dB (1)		19		dBm
NF	Noise figure @ Attenuator state 0dB		7		dB
VSWRin	Input VSWR all attenuator states		2.4:1		
VSWRout	Output VSWR all attenuator states		2.0:1		
Vd	Drain bias DC voltage (Pads B,D)		4.5		V
Id	Bias current @ small signal		190	250	mA
Vc	Control voltage for Attenuator bits	-5		0	V

(1) These values are representative for on-wafer measurements that are made without bonding wires at the RF ports.

*preliminary***Absolute Maximum Ratings**T<sub>amb.</sub> = 25°C (1)

Symbol	Parameter	Values	Unit
V <sub>d</sub>	Maximum Drain bias voltage ( Pads B,D)	+5	V
I <sub>d</sub>	Drain bias current with V <sub>d</sub> =4.5V	320	mA
V <sub>g</sub>	Gate bias voltage (Pads A, E)	-2 to +0.4	V
V <sub>c</sub>	Attenuator bits control voltage	-7 to +0.6	V
P <sub>in</sub>	Maximum input power overdrive (2)	+20.0	dBm
T <sub>ch</sub>	Maximum channel temperature	+175	°C
T <sub>a</sub>	Operating temperature range	-40 to +70	°C
T <sub>stg</sub>	Storage temperature range	-55 to +125	°C

(1) Operation of this device above anyone of these parameters may cause permanent damage.

(2) Duration &lt; 1s.

**4bit VGA Control interface**

The attenuator states are controlled by 8 voltages.

state	Theoretical attenuation dB	Voltage CONTROL PAD							
		10A (V)	10B (V)	5A (V)	5B (V)	2.5A (V)	2.5B (V)	20A (V)	20B (V)
0	0 référence	-5	0	-5	0	-5	0	-5	0
1	2.5	-5	0	-5	0	0	-5	-5	0
2	5	-5	0	0	-5	-5	0	-5	0
3	7.5	-5	0	0	-5	0	-5	-5	0
4	10	0	-5	-5	0	-5	0	-5	0
5	12.5	0	-5	-5	0	0	-5	-5	0
6	15	0	-5	0	-5	-5	0	-5	0
7	17.5	0	-5	0	-5	0	-5	-5	0
8	20	-5	0	-5	0	-5	0	0	-5
9	22.5	-5	0	-5	0	0	-5	0	-5
10	25	-5	0	0	-5	-5	0	0	-5
11	27.5	-5	0	0	-5	0	-5	0	-5
12	30	0	-5	-5	0	-5	0	0	-5
13	32.5	0	-5	-5	0	0	-5	0	-5
14	35	0	-5	0	-5	-5	0	0	-5
15	37.5	0	-5	0	-5	0	-5	0	-5

Typical chip on wafer Sij parameters for reference state

*preliminary*

Tamb 25°C, B=D=4.5V, Id=190mA, 10A, 5A, 2.5A, 20A = -5V, 10B, 5B, 2.5B, 20B =0V

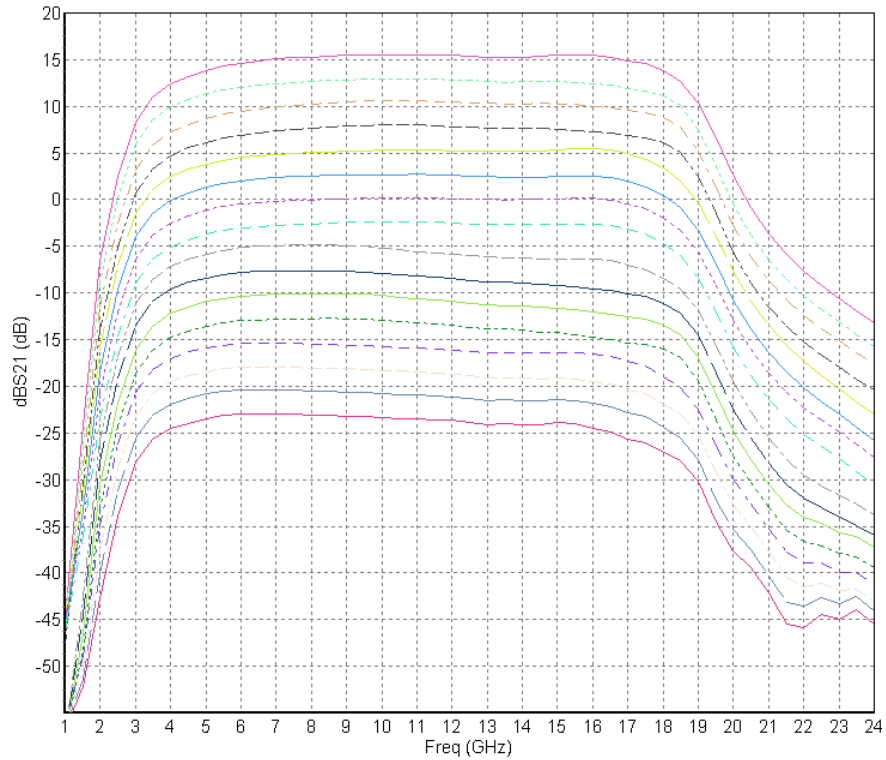
Freq (GHz)	dB(S11)	P(S11) (°)	dB(S21)	P(S21) (°)	dB(S12)	P(S12) (°)	dB(S22)	P(S22) (°)
1.0	-0.8	-42.4	-44.8	-114.9	-69.9	-91.3	-3.3	-59.4
1.5	-1.5	-62.3	-24.1	-166.4	-69.2	-148.8	-4.6	-89.6
2.0	-2.1	-81.0	-6.6	156.9	-67.0	-165.4	-7.2	-122.7
2.5	-2.8	-99.6	2.5	94.4	-61.4	-179.5	-10.5	-160.5
3.0	-4.1	-116.9	8.3	37.6	-69.4	74.2	-14.8	147.5
3.5	-5.1	-133.6	11.0	-17.7	-86.1	97.0	-17.4	88.8
4.0	-6.3	-148.7	12.4	-65.1	-78.4	133.3	-16.9	43.1
4.5	-7.8	-162.3	13.3	-107.0	-72.8	112.9	-15.5	15.9
5.0	-9.3	-175.1	13.9	-145.1	-70.0	77.8	-14.4	-2.5
5.5	-10.7	174.7	14.3	178.9	-68.7	34.4	-13.5	-17.5
6.0	-12.2	167.3	14.6	144.5	-66.8	-5.4	-12.9	-30.6
6.5	-13.8	161.4	14.9	111.4	-64.9	-37.6	-12.4	-42.3
7.0	-15.0	157.0	15.1	79.3	-67.2	-61.6	-12.1	-54.0
7.5	-15.6	155.3	15.2	47.9	-62.7	-85.6	-12.0	-66.0
8.0	-16.2	156.1	15.3	16.9	-59.7	-109.9	-12.2	-78.5
8.5	-16.6	154.3	15.4	-13.7	-57.5	-138.0	-12.7	-90.1
9.0	-16.1	151.1	15.5	-44.0	-55.6	-167.3	-13.6	-102.2
9.5	-15.3	148.6	15.5	-73.9	-54.7	171.2	-15.1	-113.3
10.0	-14.6	145.0	15.5	-103.8	-53.2	136.4	-17.3	-123.0
10.5	-14.0	136.7	15.5	-133.5	-54.7	117.6	-20.4	-125.3
11.0	-13.0	127.2	15.5	-163.1	-56.0	96.6	-23.7	-113.1
11.5	-12.2	119.0	15.5	167.2	-56.4	74.2	-24.5	-88.9
12.0	-11.8	108.7	15.5	137.5	-59.8	43.6	-22.9	-73.3
12.5	-11.5	96.1	15.4	107.7	-76.5	22.9	-21.9	-66.9
13.0	-11.2	83.5	15.3	77.9	-65.0	178.8	-20.1	-59.5
13.5	-11.6	73.4	15.2	49.1	-60.2	148.9	-17.4	-59.3
14.0	-12.5	64.6	15.3	20.1	-59.5	146.9	-15.1	-68.1
14.5	-13.1	57.6	15.4	-10.6	-55.2	142.1	-13.5	-81.7
15.0	-13.2	52.4	15.5	-42.1	-49.9	141.5	-12.6	-99.9
15.5	-14.1	44.8	15.5	-74.7	-45.5	117.2	-12.6	-121.4
16.0	-15.7	40.2	15.4	-108.3	-43.7	87.3	-13.9	-146.5
16.5	-18.0	39.2	15.3	-143.1	-42.0	61.2	-16.6	-177.9
17.0	-19.7	66.0	14.9	-178.3	-41.7	36.3	-21.3	136.0
17.5	-16.8	97.0	14.5	144.9	-41.5	14.5	-22.3	46.6
18.0	-12.7	96.4	13.8	105.1	-41.0	-13.7	-17.6	-12.9
18.5	-9.9	89.2	12.7	64.1	-42.1	-42.4	-15.1	-51.6
19.0	-7.1	80.6	10.3	19.1	-45.0	-76.5	-15.6	-84.5
19.5	-5.3	68.5	6.6	-19.0	-50.6	-91.9	-20.1	-107.2
20.0	-4.1	54.4	2.6	-47.9	-54.4	-69.2	-29.1	-59.0
20.5	-3.3	41.5	-0.8	-70.2	-53.6	-67.9	-19.5	-18.0
21.0	-2.8	30.8	-3.6	-89.1	-54.2	-66.0	-14.7	-29.5
21.5	-2.6	21.1	-5.8	-107.0	-54.2	-73.1	-12.0	-43.1
22.0	-2.4	11.6	-7.7	-125.3	-55.5	-89.7	-10.4	-56.0
22.5	-2.2	3.5	-9.3	-143.8	-58.9	-95.4	-9.4	-69.1
23.0	-2.2	-3.3	-10.6	-162.9	-62.1	-90.4	-8.8	-81.5
23.5	-2.1	-10.1	-11.9	176.9	-65.9	-60.7	-8.6	-92.4
24.0	-2.1	-16.9	-13.2	156.5	-62.2	-32.7	-8.6	-102.8

Typical on wafer Measurements @ 25°C

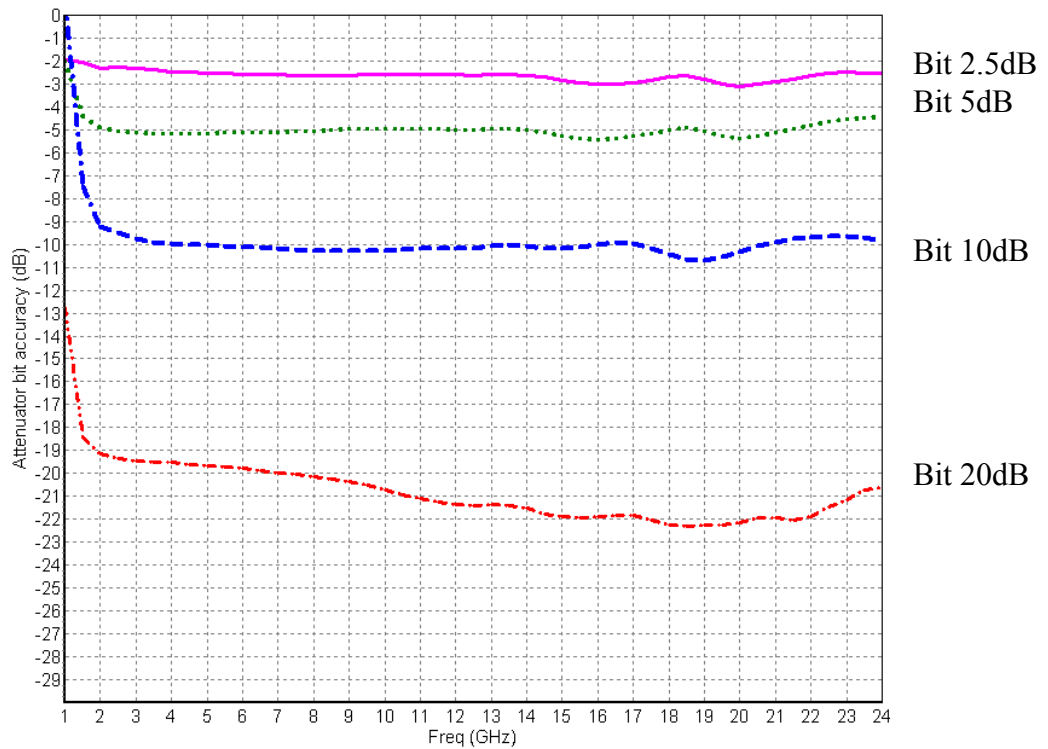
Bias conditions:  $V_d=4.5V$ ,  $V_g$  tuned for  $I_d = 190mA$

preliminary

Linear Gain versus attenuator states

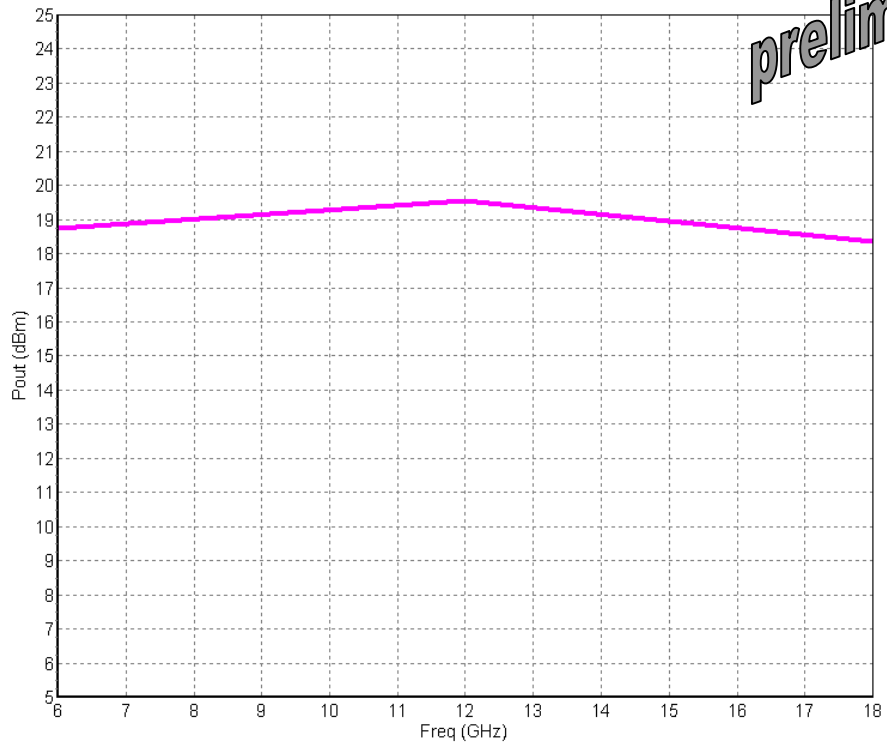


Attenuator accuracy vs frequency for main states

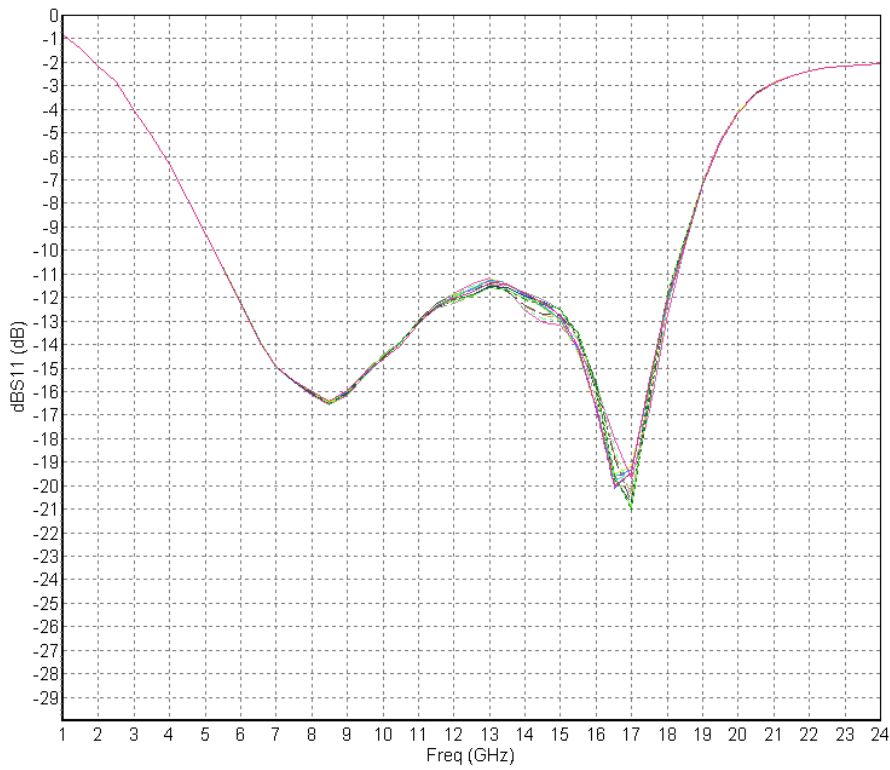


Saturated output power @ nominal state

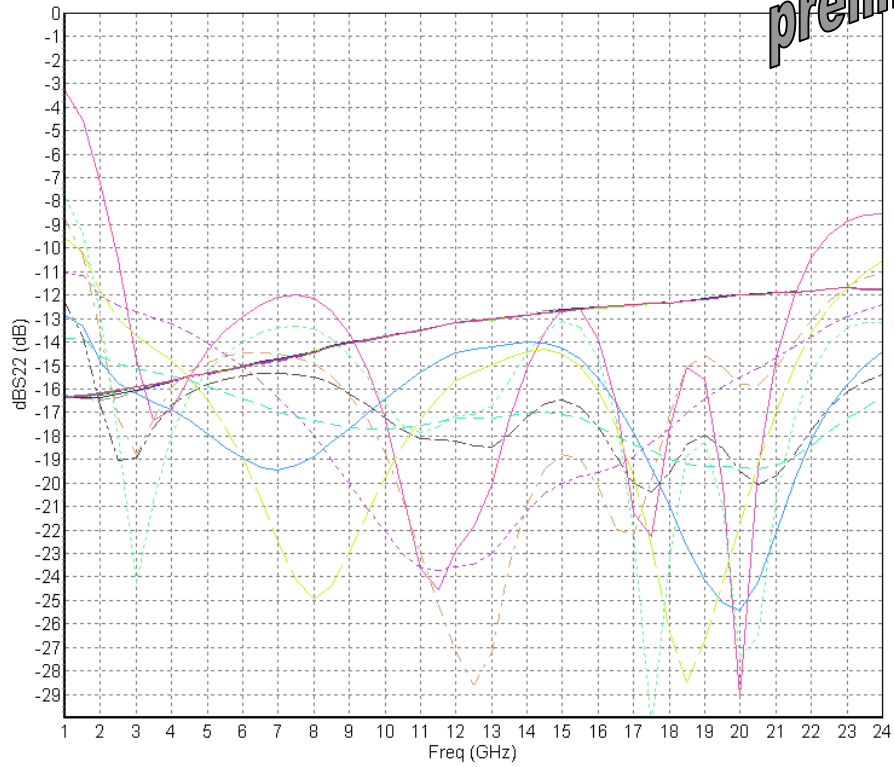
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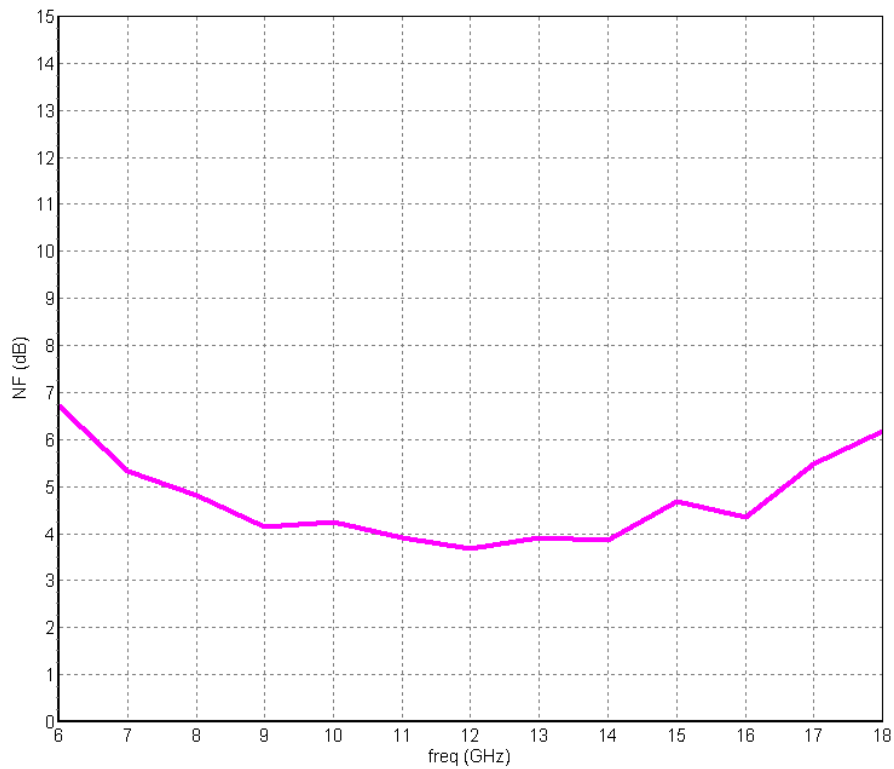
dB(S11) versus frequency for all states



dB(S22) versus frequency for all states



Noise Figure vs frequency @ nominal state

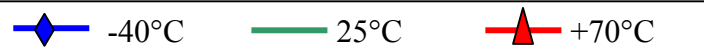
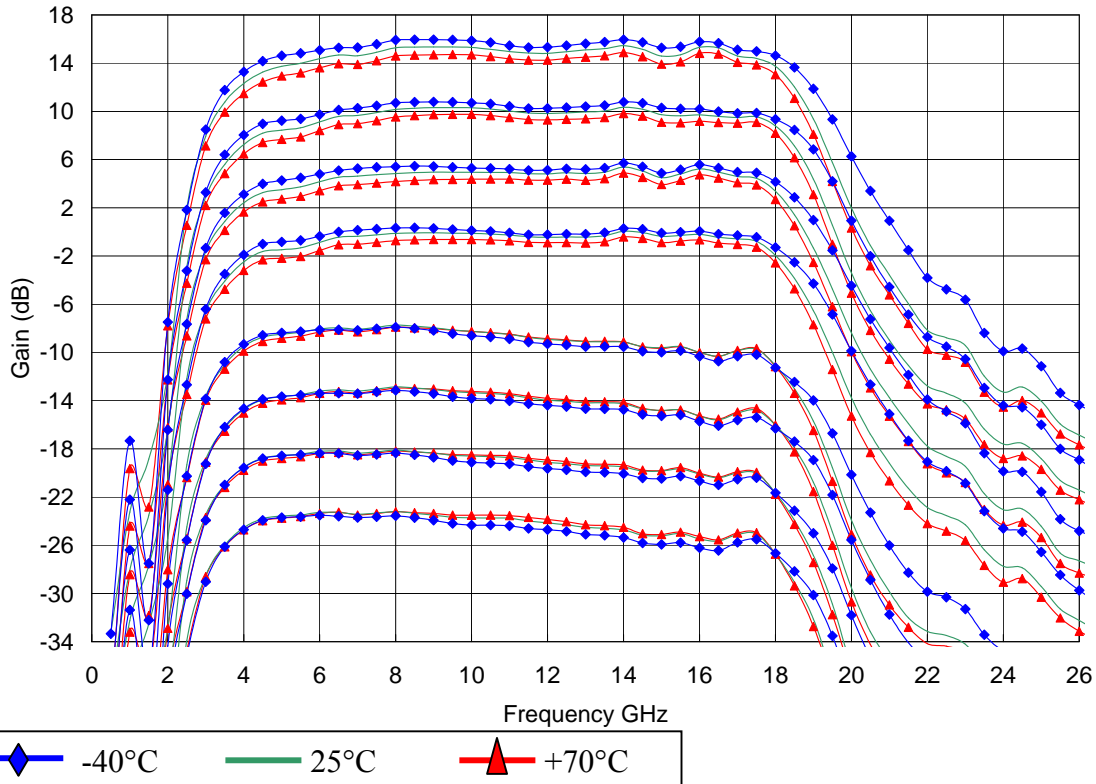


## Typical test fixture Measurements

Bias conditions:  $V_d=4.5V$ ,  $V_g$  tuned for  $I_d = 190mA$

*preliminary*

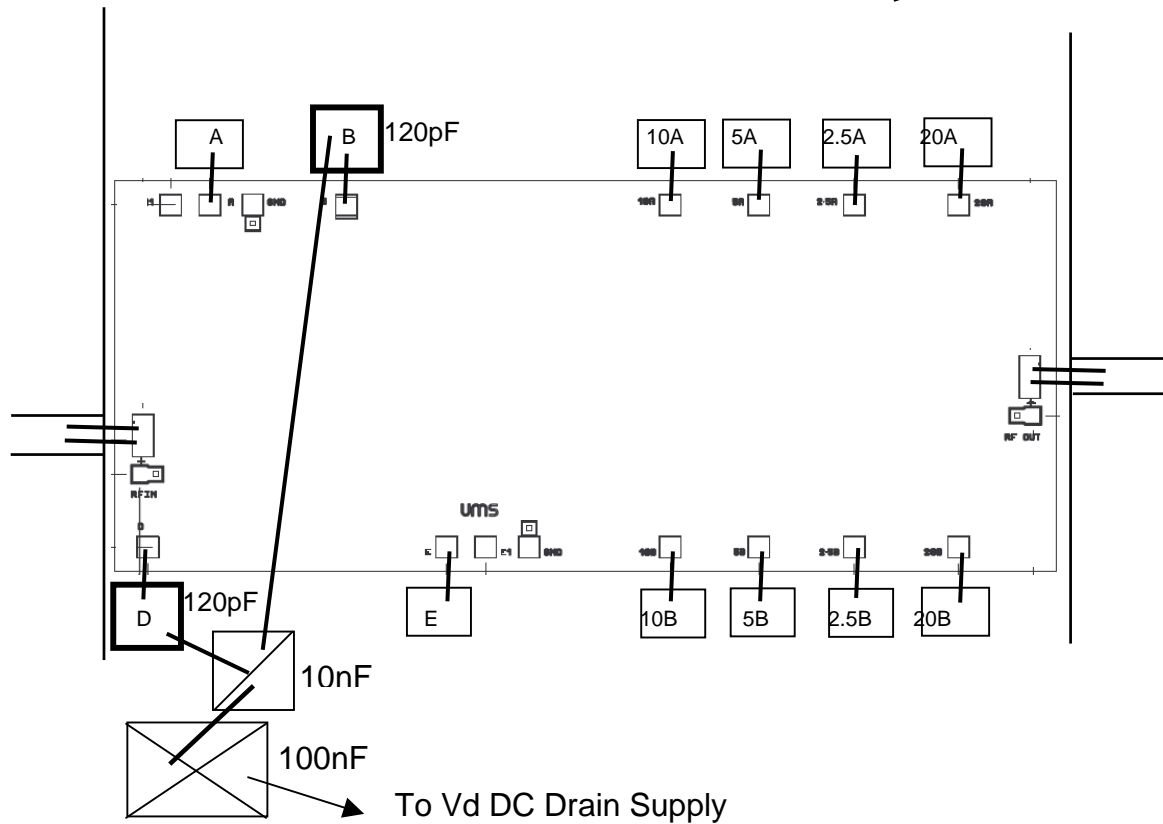
### Linear Gain versus attenuation states & temperature





Chip Assembly and Mechanical Data

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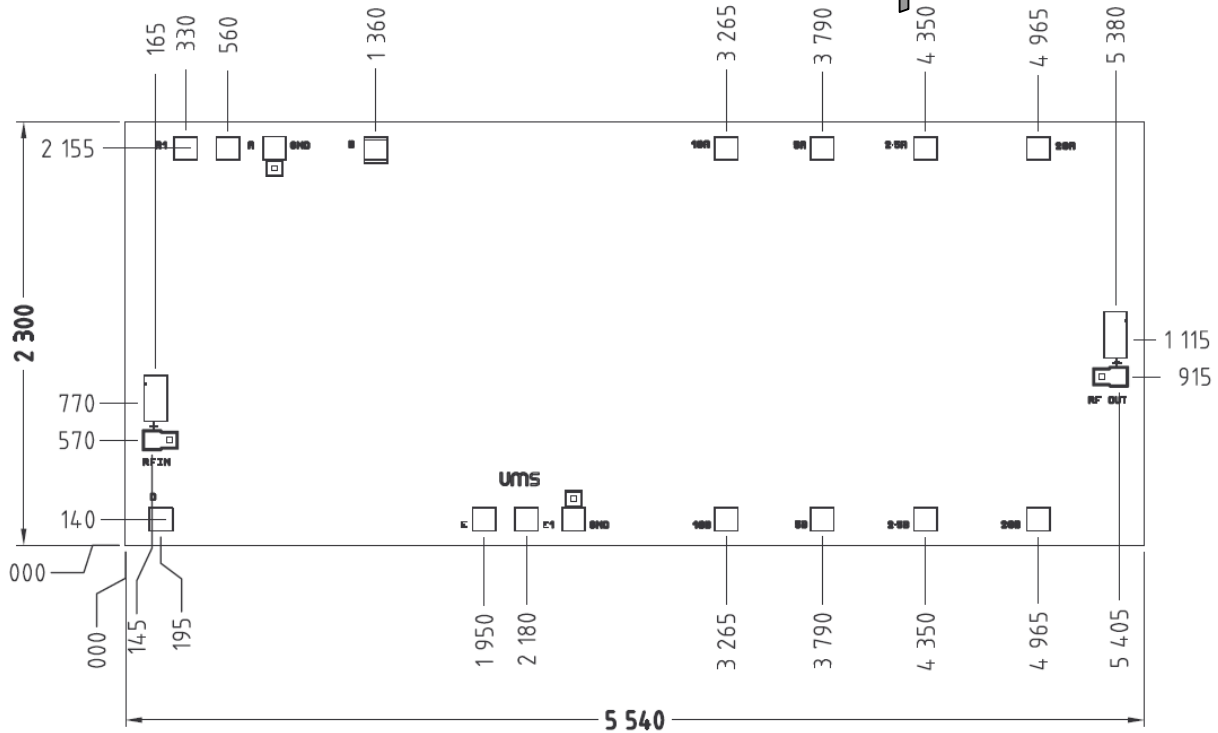
Note : Supply feed should be capacitively bypassed. 25µm diameter gold wire is to be preferred.

Recommended circuit bonding table

Label	Type	Decoupling	Comment
10A, 10B	Vc	Not required	10dB pad control
5A, 5B	Vc	Not required	5dB pad control
2.5A, 2.5B	Vc	Not required	2.5dB pad control
20A, 20B	Vc	Not required	20dB pad control
<b>B</b>	<b>Vd</b>	<b>120pF / 10nF</b>	<b>Drain Supply</b>
<b>D</b>	<b>Vd</b>	<b>120pF / 10nF</b>	<b>Drain Supply</b>
A	Vg	Not required	Gate Supply
E	Vg	Not required	Gate Supply

Bonding pad positions

preliminary



UNITS :  $\mu\text{m}$   
Tol :  $\pm 35\mu\text{m}$

( Chip thickness : 100 $\mu\text{m}$ )

Ordering Information

Chip form : CHA3514-99F/00

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